

AM1031C – Amplifier

20 MHz to 8.0 GHz Gain Block



Description

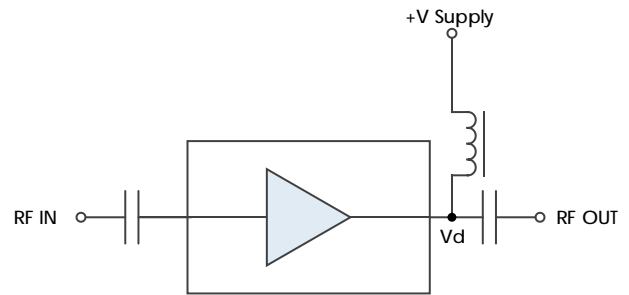
AM1031C is a high dynamic range cascadable gain block covering the 20 MHz to 8 GHz frequency range. The device exhibits low noise figure and high third order intercept performance while also providing excellent gain stability over the operating temperature range. With internal 50Ω matching and packaged in a 3mm QFN or a shielded module, the AM1031C represents a compact total PCB footprint.



Features

- 13 dB Gain
- 2.2 dB Noise Figure
- +32 dBm OIP3
- +17 dBm P1dB
- +3.3V, 56 mA
- 3mm QFN Package
- -40C to +85C Operation
- Unconditionally Stable

Functional Diagram



Characteristic Performance

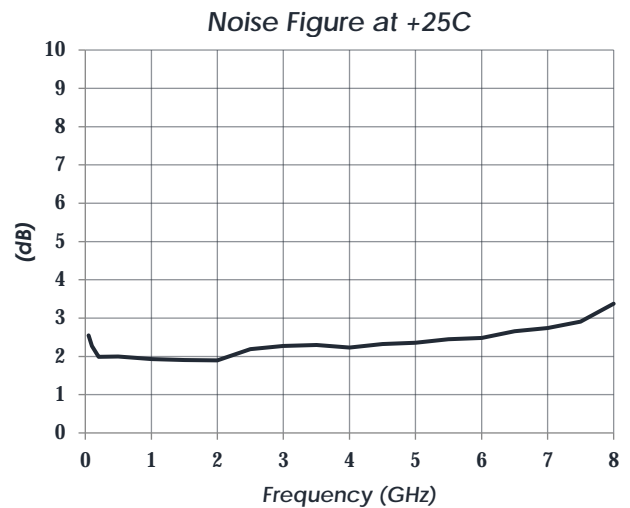
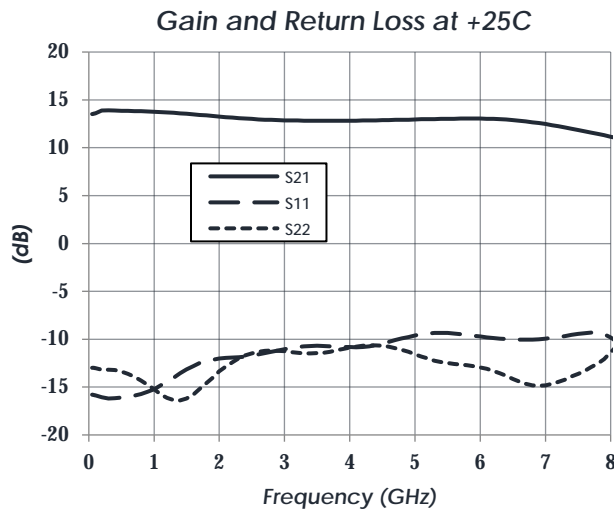


Table of Contents

Description	1	Thermal Information	4
Features.....	1	DC Electrical Characteristics.....	5
Functional Diagram.....	1	RF Performance.....	5
Characteristic Performance	1	Typical Performance	6
Revision History	2	Typical Application.....	8
Pin Layout and Definitions.....	3	Part Ordering Details.....	8
Specifications	4	Evaluation PC Board	9
Absolute Maximum Ratings.....	4	Related Parts.....	9
Handling Information.....	4	Component Compliance Information.....	10
Recommended Operating Conditions....	4		

Revision History

Date	Revision Number	Notes
May 14, 2018	0	Preliminary Release
May 24, 2018	1	Initial Release
April 9, 2019	2	Pinout Corrected, Functional Diagram Added, Plots Resized, Part Picture Added.
November 26, 2019	3	RF-Shielded Module Information Added, Part Ordering Details Added
August 25, 2020	4	Thermal Resistance Information Corrected. Package and Module Information Moved to Main Product Page on Website.
September 16, 2020	4.1	Minor Formatting Issues Fixed. Storage Temperature Updated.

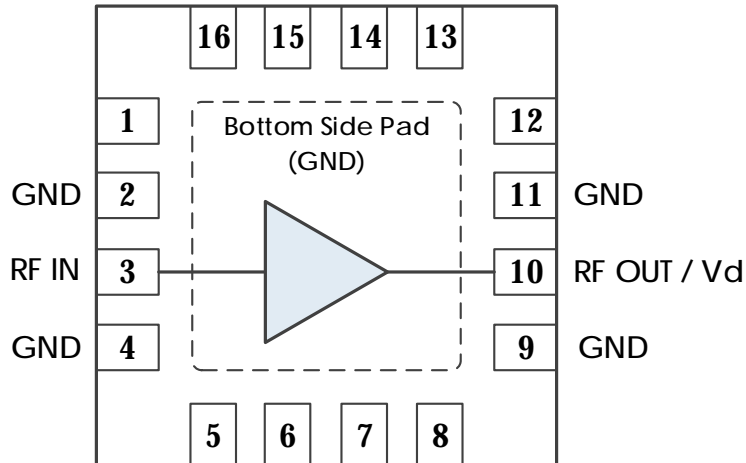
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Pin Layout and Definitions

NOTE: All Non-Named Pins Are NC or GND



Pin Number	Pin Name	Pin Function
1	NC	Not Connected*
2	GND	Ground – Common
3	RF In	RF Input – 50 Ohms – DC Coupled, External DC Block Required
4	GND	Ground – Common
5 – 8	NC	Not Connected*
9	GND	Ground – Common
10	RF Out/ Vd	RF Output and DC Power Input – 50 Ohms – DC Coupled, External DC Block Required
11	GND	Ground – Common
12 – 16	NC	Not Connected*
Bottom Pad	GND	Ground – Common

*Note: NC pins may be grounded or left open.

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20 MHz to 8.0 GHz Gain Block



Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Device Voltage, Vd	-0.3 V	+3.4 V
RF Input Power		+16 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-55 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.
Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+2.8 V	+3.3 V	+3.7 V
Device Voltage, Vd	+2.5 V	+3.0 V	+3.4 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C

Thermal Information

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance (θ_{JC})	137

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DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
Device Voltage, Vd	V Supply = +3.3 V	+2.5 V	+3.0 V	+3.4 V
DC Device Current	V Supply = +3.3 V	50 mA	56 mA	62 mA
Power Dissipated	V Supply = +3.3 V		0.17 W	

RF Performance

(T = 25 °C unless otherwise specified)

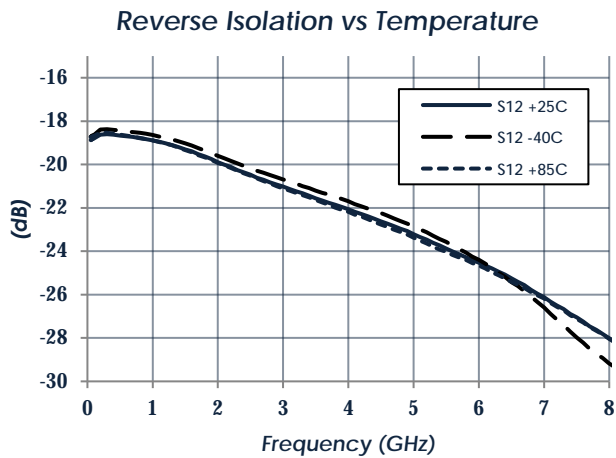
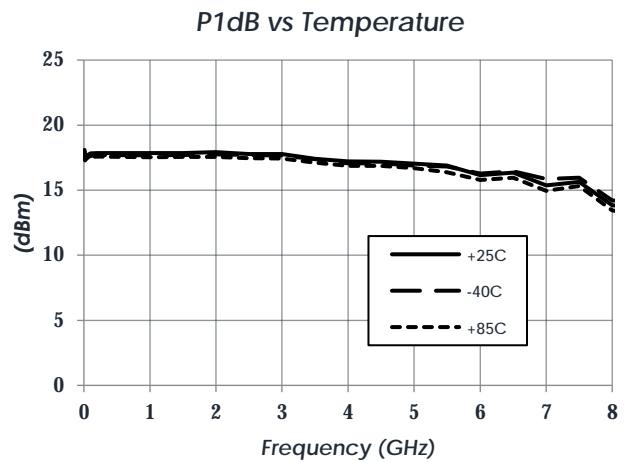
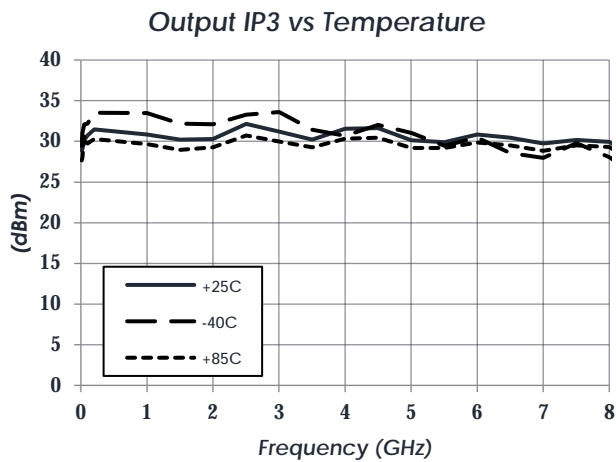
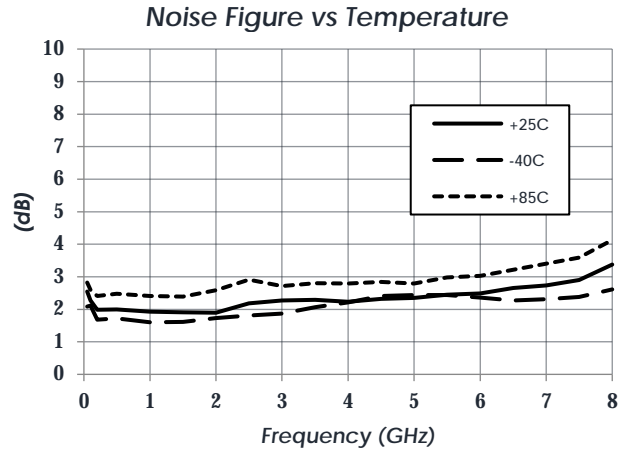
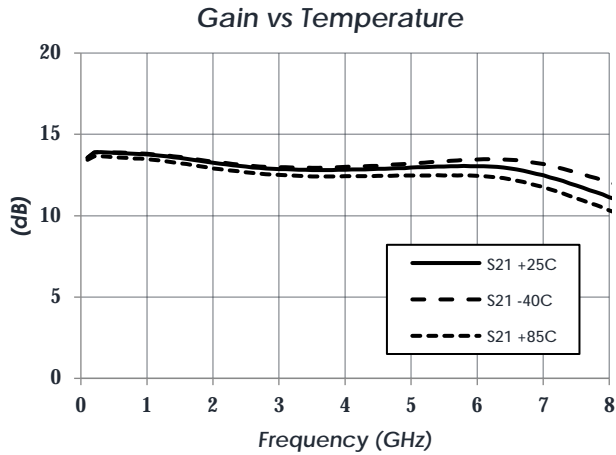
Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		20 MHz		8.0 GHz
Gain	f = 4 GHz		13 dB	
Output IP3	f = 4 GHz		+32 dBm	
Output P1dB	f = 4 GHz		+17 dBm	
Noise Figure	f = 4 GHz		2.2 dB	

AM1031C - Amplifier

20 MHz to 8.0 GHz Gain Block

Typical Performance

(V Supply = +3.3V, Device Voltage [Vd] = +3.0V, Id = 56 mA)



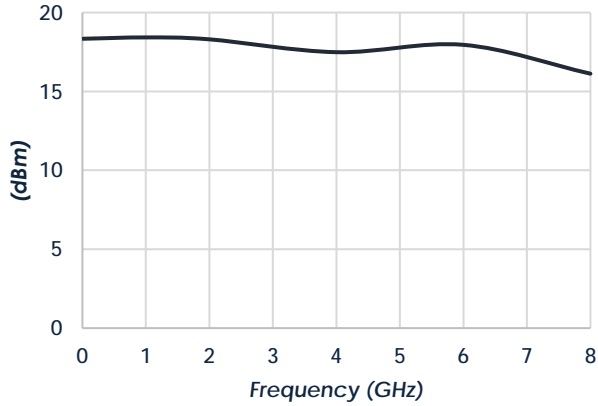
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20 MHz to 8.0 GHz Gain Block

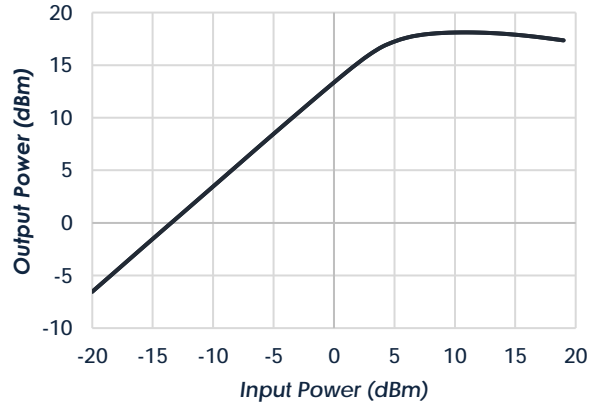
Typical Performance (continued)

(V Supply = +3.3V, Device Voltage [Vd] = +3.0V, Id = 56 mA)

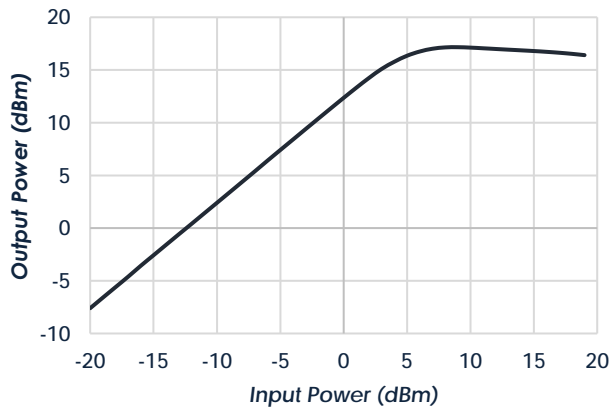
Saturated Output Power



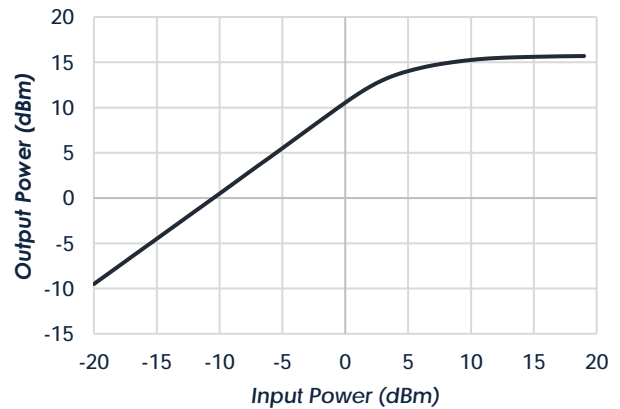
Pin vs Pout at 1GHz



Pin vs Pout at 4GHz



Pin vs Pout at 8GHz

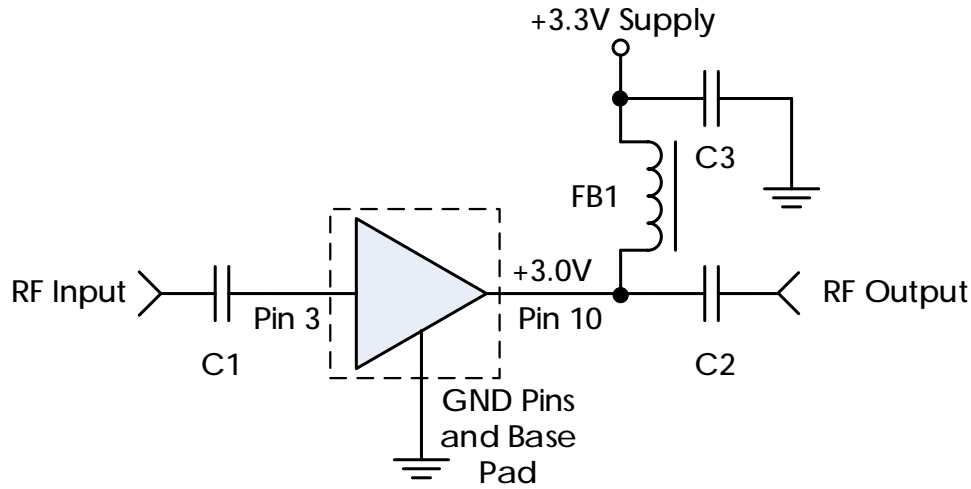


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20 MHz to 8.0 GHz Gain Block



Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1 μ F	0402BB104KW160	Passives Plus
C3	0.1 μ F	GRM155R71C104KA88	Murata
FB1	-	BLM15HG102SN1D	Murata

Notes:

1. NC pins may be grounded or left open.
2. External DC blocking capacitors and RF choke are required.
 - a. RF blocking capacitors should be high performance, low-loss, broadband capacitors for optimum performance.
 - b. Select values for the frequency range of interest.
3. No input or output matching is required.

Part Ordering Details

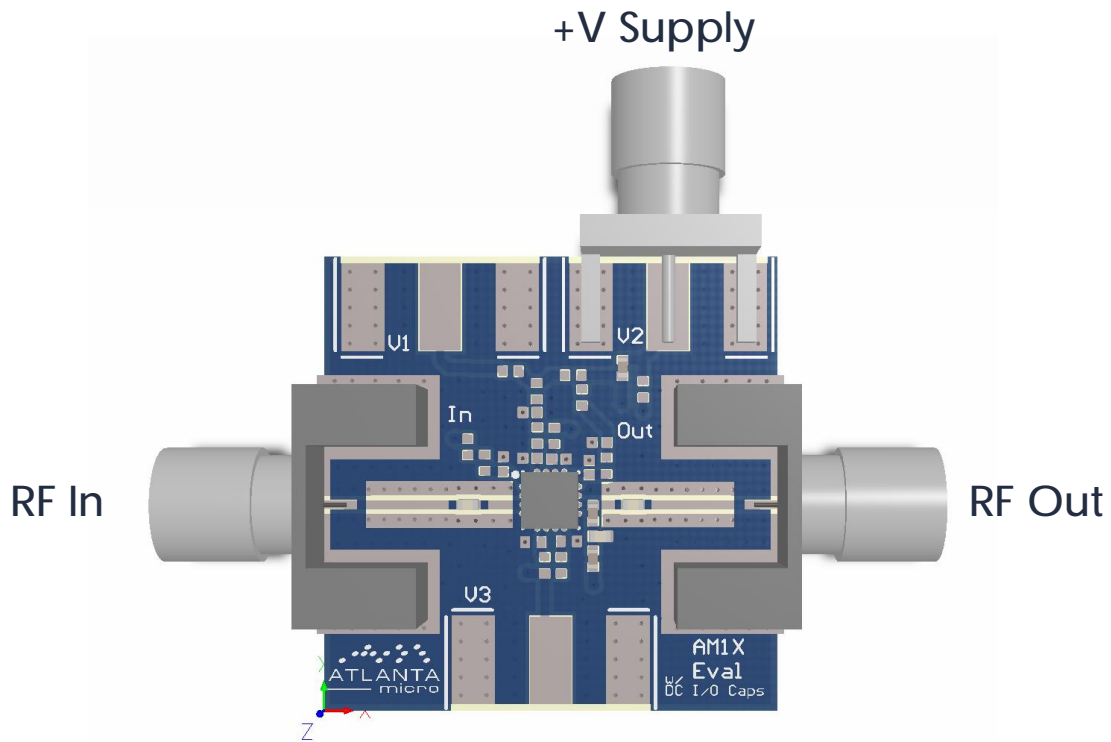
Description	Part Number
3mm 16 Lead QFN	AM1031C
AM1031C Evaluation Board	AM1031C Eval
AM1031C in 0.95" x 1.13" x 0.6" RF-Shielded Module with Integrated Bias Tee and Field Replaceable SMA Connectors	AM1031C-M

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Evaluation PC Board



Related Parts

Part Number	Description			
AM1016B	20 MHz	to	6 GHz	+3.3V Gain Block
AM1018B	20 MHz	to	6 GHz	+5.0V Gain Block
AM1018C	20 MHz	to	6 GHz	+5.0V Gain Block
AM1025B	20 MHz	to	3 GHz	High P1dB Gain Block
AM1090	DC	to	6 GHz	High P1dB Gain Block
AM1163-1	DC	to	10 GHz	Low Noise Amplifier
AM1163-2	DC	to	10 GHz	Miniature Low Noise Amplifier
AM1164-1	DC	to	8 GHz	Low Noise Amplifier
AM1164-2	DC	to	8 GHz	Miniature Low Noise Amplifier

Component Compliance Information

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Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylhexyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

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